

Product Summary

$V_{(BR)DSS}$	$R_{DS(on)TYP}$	I_D
100V	3.1mΩ@10V	180A

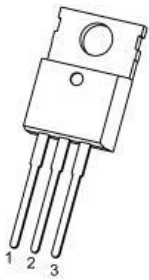
Feature

- Fast Switching
- Low Gate Charge and R_{ds(on)}
- 100% Single Pulse avalanche energy Test

Applications

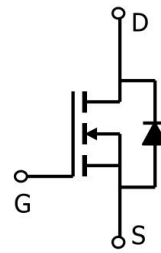
- Power switching application
- DC-DC Converter
- Power Management

Package

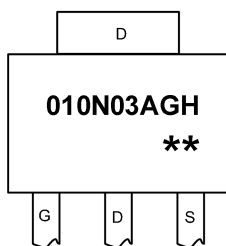


TO-220-3L-C(1:G 2:D 3:S)

Circuit diagram



Marking



010N03AGH : Product code
** : Week code

Absolute maximum ratings (Ta=25°C, unless otherwise noted)

Parameter	Symbol	Rating	Unit
Drain source voltage	V_{DS}	100	V
Gate source voltage	V_{GS}	± 20	V
Continuous drain current(Tc=25°C)	I_D	180	A
Pulsed drain current	I_{DM}	720	A
Power dissipation(Tc=25°C)	P_D	280	W
Single pulsed avalanche energy ¹⁾	E_{AS}	1600	mJ
Thermal resistance, junction-case	$R_{\theta JC}$	0.44	°C/W
Operation and storage temperature	T_{stg}, T_j	-55 to 150	°C

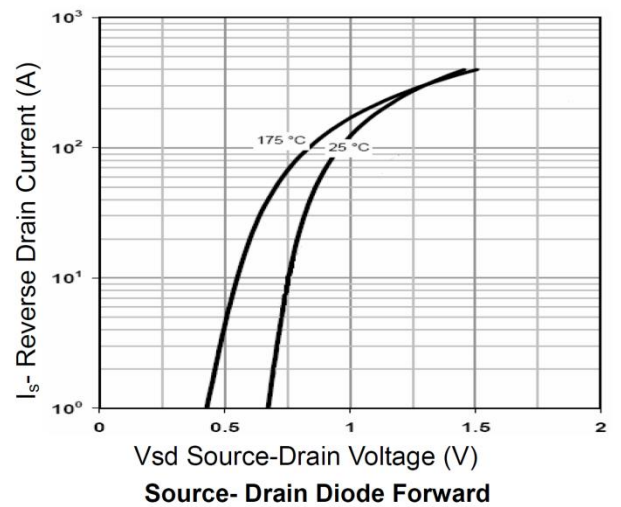
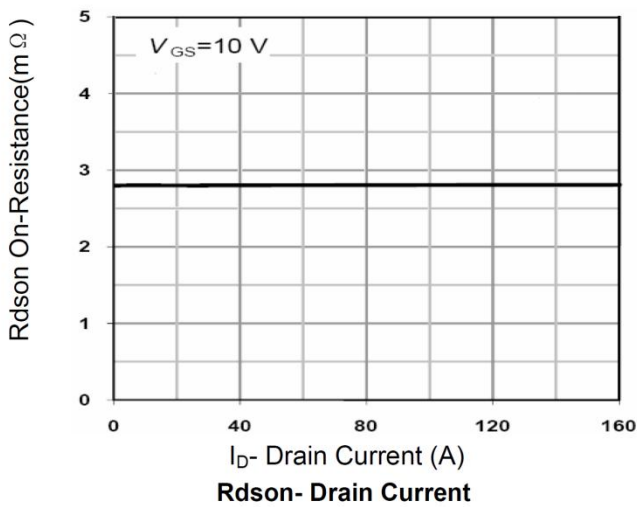
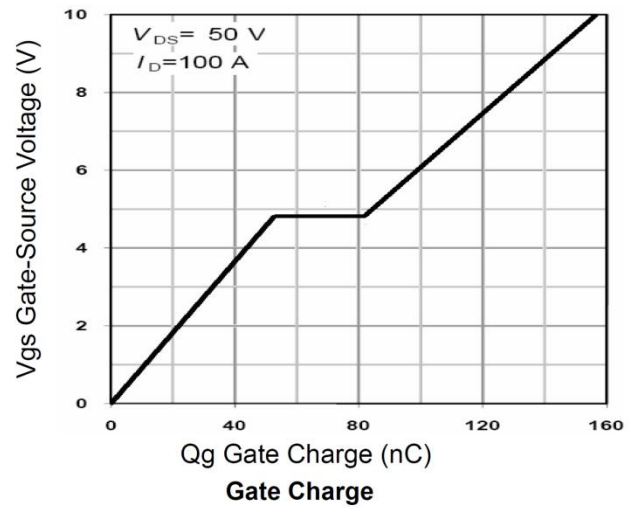
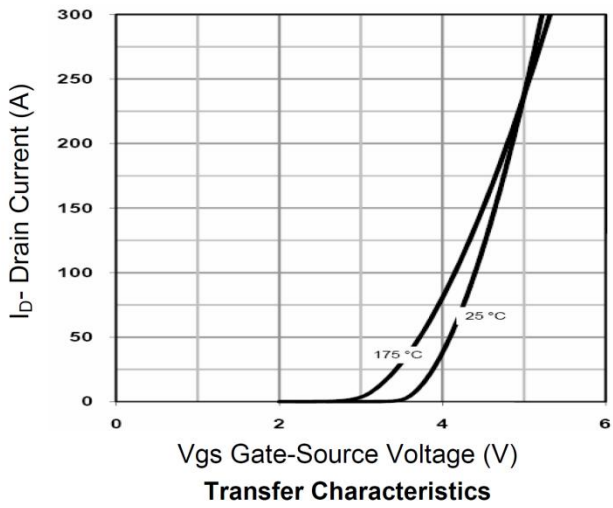
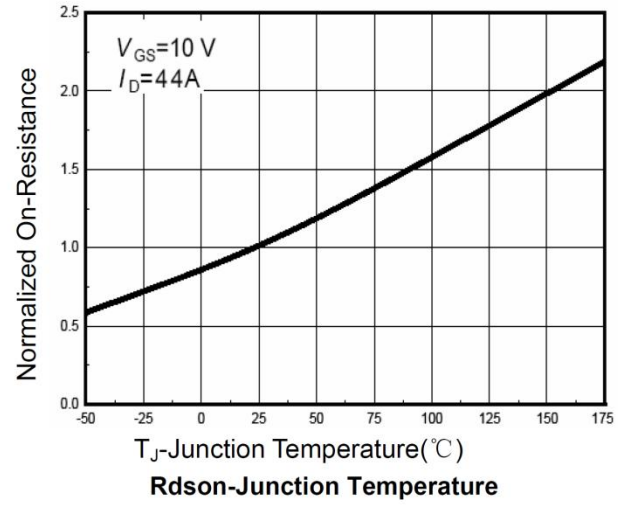
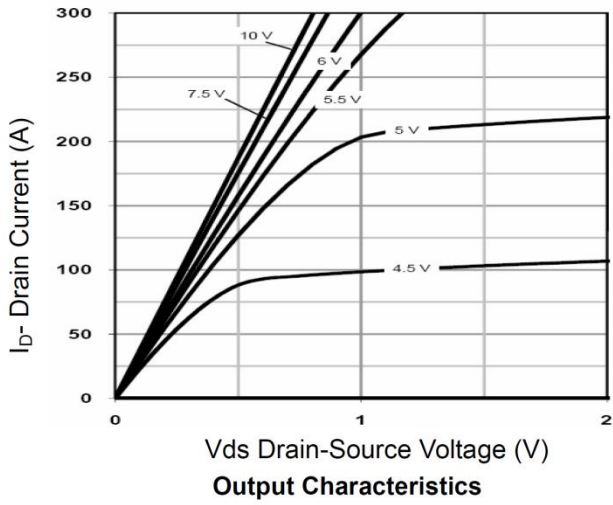
Electrical characteristics (Ta=25°C, unless otherwise noted)

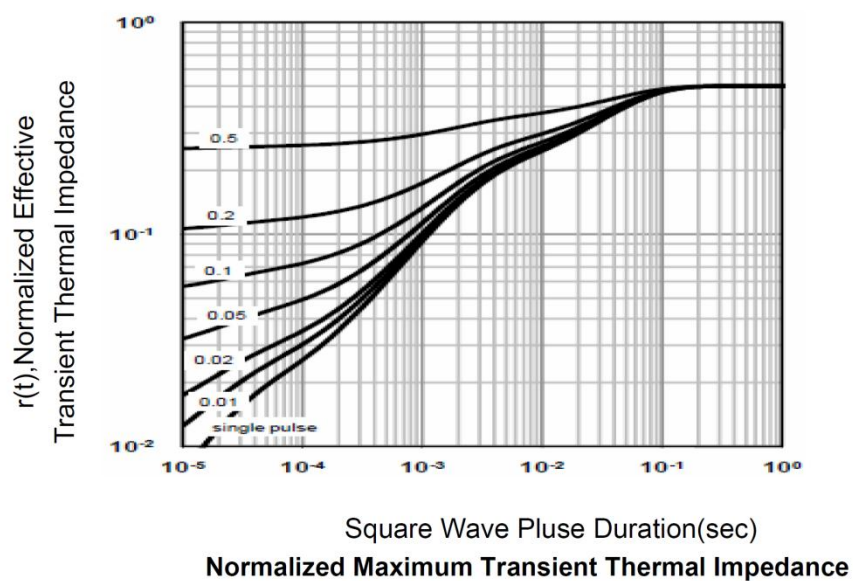
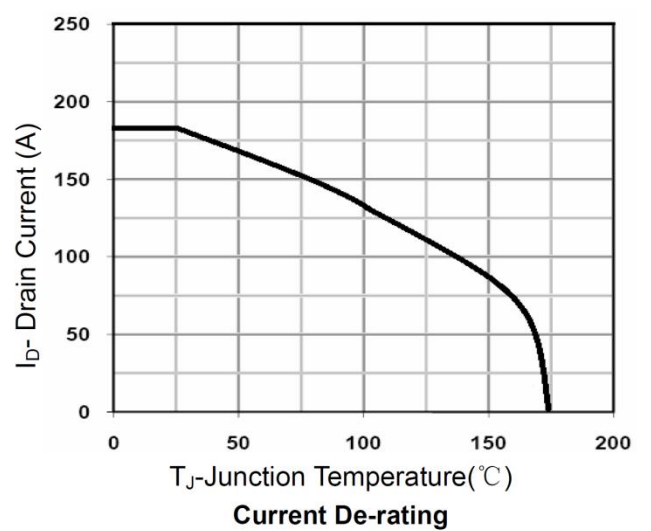
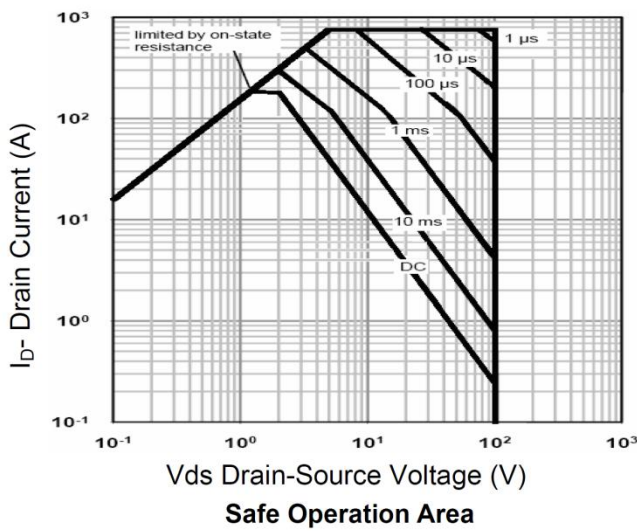
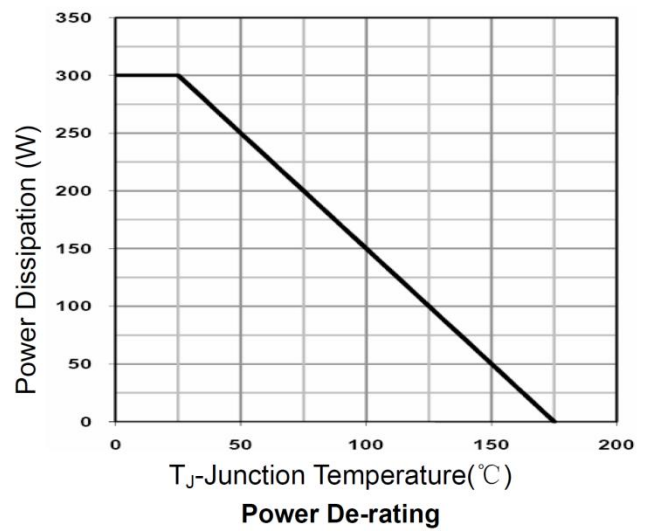
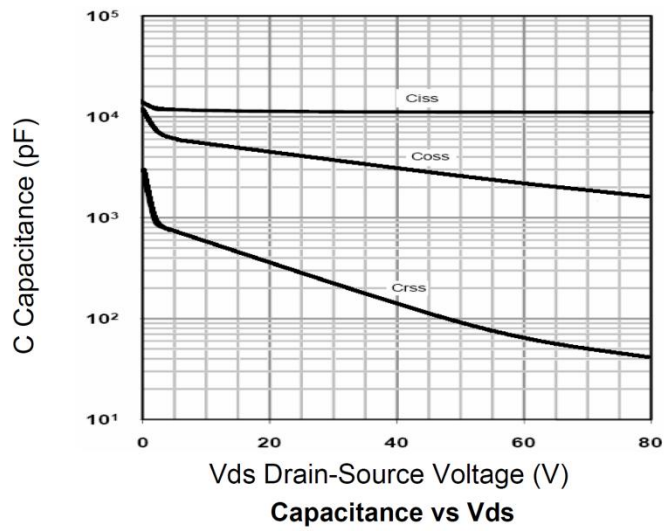
Characteristics	Symbol	Test Condition	Min	Typ	Max	Unit
Static Characteristics						
Drain-Source Breakdown Voltage	BV_{DSS}	$I_D = 250\mu A, V_{GS} = 0V$	100	-	-	V
Drain Cut-Off Current	I_{DSS}	$V_{DS} = 80V, V_{GS} = 0V$	-	-	1	μA
Gate Leakage Current	I_{GSS}	$V_{GS} = \pm 20V, V_{DS} = 0V$	-	-	± 0.1	
Gate Threshold Voltage	$V_{GS(th)}$	$V_{DS} = V_{GS}, I_D = 250\mu A$	2.0	2.5	4.0	V
Drain-Source ON Resistance	$R_{DS(ON)}$	$V_{GS} = 10V, I_D = 30A$	-	3.1	3.9	m Ω
Dynamic Characteristics						
Input Capacitance	C_{iss}	$V_{DS} = 50V, V_{GS} = 0V, f = 1.0MHz$	-	6980	-	pF
Output Capacitance	C_{oss}		-	653	-	
Reverse Transfer Capacitance	C_{rss}		-	24	-	
Switching Characteristics						
Total Gate Charge	Q_g	$V_{DS} = 50V, V_{GS} = 10V, I_D = 100A$	-	158	-	nC
Gate-Source Charge	Q_{gs}		-	53	-	
Gate-Drain Charge	Q_{gd}		-	27	-	
Turn-On Delay Time	$t_{d(on)}$	$V_{GS} = 10V, V_{DS} = 50V, I_D = 100A, R_G = 6\Omega$	-	26	-	ns
Rise Time	t_r		-	75	-	
Turn-Off Delay Time	$t_{d(off)}$		-	87	-	
Fall Time	t_f		-	30	-	
Drain-Source Body Diode Characteristics						
Source-Drain Diode Forward Voltage	V_{SD}	$I_S = 1A, V_{GS} = 0V$	-	-	1.2	V

Note:

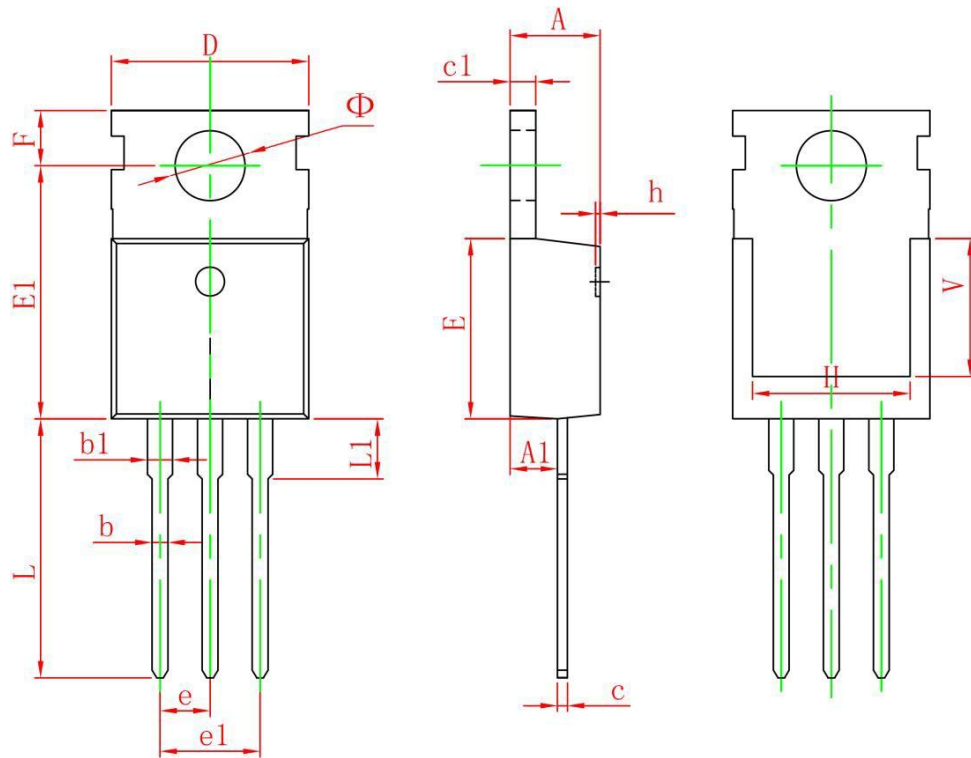
- E_{AS} is tested at starting $T_j = 25^\circ C, V_{DD} = 50V, V_{GS} = 10V, L = 0.5mH, R_g = 25\Omega$;

Typical Characteristics





TO-220-3L-C Package Information



Symbol	Dimensions In Millimeters		Dimensions In Inches	
	Min.	Max.	Min.	Max.
A	4.400	4.600	0.173	0.181
A1	2.250	2.550	0.089	0.100
b	0.710	0.910	0.028	0.036
b1	1.170	1.370	0.046	0.054
c	0.330	0.650	0.013	0.026
c1	1.200	1.400	0.047	0.055
D	9.910	10.250	0.390	0.404
E	8.950	9.750	0.352	0.384
E1	12.650	13.050	0.498	0.514
e	2.540 TYP.		0.100 TYP.	
e1	4.980	5.180	0.196	0.204
F	2.650	2.950	0.104	0.116
H	7.900	8.100	0.311	0.319
h	0.000	0.300	0.000	0.012
L	12.900	13.400	0.508	0.528
L1	2.850	3.250	0.112	0.128
V	6.900 REF.		0.276 REF.	
Φ	3.400	3.800	0.134	0.150